74ALVC32

Quad 2-input OR gate Rev. 3 — 20 January 2014

Product data sheet

1. **General description**

The 74ALVC32 is a quad 2-input OR gate.

Schmitt trigger action on all inputs makes the device tolerant of slow rise and fall times.

2. **Features and benefits**

- Wide supply voltage range from 1.65 V to 3.6 V
- 3.6 V tolerant inputs/outputs
- CMOS low power consumption
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Power-down mode
- Latch-up performance exceeds 250 mA
- Complies with JEDEC standards:
 - ◆ JESD8-7 (1.65 V to 1.95 V)
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - ♦ HBM JESD22-A114E exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V

Ordering information 3.

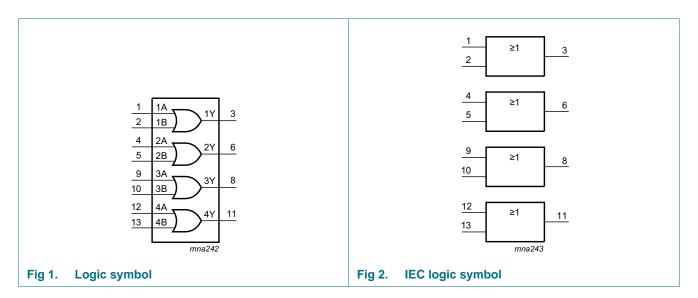
Table 1. **Ordering information**

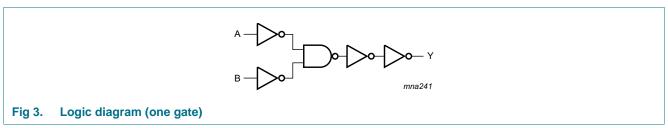
Type number	Package									
	Temperature range	Name	Description	Version						
74ALVC32D	–40 °C to +85 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1						
74ALVC32PW	–40 °C to +85 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1						
74ALVC32BQ	–40 °C to +85 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 \times 3 \times 0.85 mm	SOT762-1						



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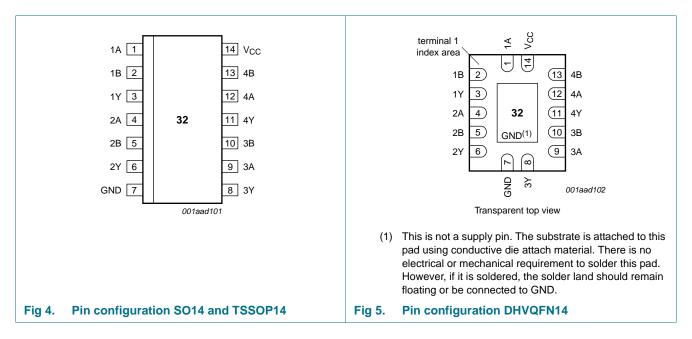
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
nA	1, 4, 9, 12	data input
nB	2, 5, 10, 13	data input
nY	3, 6, 8, 11	data output
V_{CC}	14	supply voltage
GND	7	ground (0 V)

6. Functional description

Table 3. Function table[1]

Input nA	Input nB	Output nY
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

^[1] H = HIGH voltage level L = LOW voltage level

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage			-0.5	+4.6	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0 \text{ V}$		-	±50	mA
Vo	output voltage	output HIGH or LOW state	[1] [2]	-0.5	$V_{CC} + 0.5$	V
		output 3-state		-0.5	+4.6	V
		power-down mode, $V_{CC} = 0 V$	[2]	-0.5	+4.6	V
I _O	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$	<u>[3]</u>	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] When $V_{CC} = 0 \text{ V}$ (power-down mode), the output voltage can be 3.6 V in normal operation.

^[3] For SO14 packages: above 70 °C derate linearly with 8 mW/K.
For TSSOP14 packages: above 60 °C derate linearly with 5.5 mW/K.
For DHVQFN14 packages: above 60 °C derate linearly with 4.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.65	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	output HIGH or LOW state	0	V_{CC}	V
	input voltage output voltage ambient temperature	output 3-state	0	3.6	V
		power-down mode; V _{CC} = 0 V	0	3.6	3.6 V V _{CC} V 3.6 V 485 °C 20 ns/V
T _{amb}	ambient temperature	in free air	-40	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$	0	20	ns/V
		V _{CC} = 2.7 V to 3.6 V	0	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} =	$T_{amb} = -40$ °C to +85 °C					
			Min	Typ[1]	Max				
V_{IH}	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	V			
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	V			
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	V			
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	V			
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V			
		V _{CC} = 2.7 V to 3.6 V	-	-	8.0	V			
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}							
		$I_{O} = -100 \mu A$; $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	$V_{CC}-0.2$	-	-	V			
		$I_O = -6 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.25	1.51	-	V			
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.8	2.10	-	V			
		$I_{O} = -18 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.7	2.01	-	V			
		$I_O = -12$ mA; $V_{CC} = 2.7$ V	2.2	2.53	-	V			
		$I_{O} = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	2.76	-	V			
		$I_O = -24$ mA; $V_{CC} = 3.0$ V	2.2	2.68	-	V			
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}							
		I_O = 100 μ A; V_{CC} = 1.65 V to 3.6 V	-	-	0.2	V			
		$I_{O} = 6 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	0.11	0.3	V			
		$I_{O} = 12 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	0.17	0.4	V			
		$I_O = 18 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	0.25	0.6	V			
		$I_{O} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	0.16	0.4	V			
		I_{O} = 18 mA; V_{CC} = 3.0 V	-	0.23	0.4	V			
		$I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.30	0.55	V			
I	input leakage current	$V_{CC} = 3.6 \text{ V}; V_{I} = 3.6 \text{ V or GND}$	-	±0.1	±5	μΑ			
l _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}$; V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V	-	±0.1	±10	μΑ			

Table 6. Static characteristics ... continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} :	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$				
			Min	Typ[1]	Max			
I _{CC}	supply current	$V_{CC} = 3.6 \text{ V}; V_I = V_{CC} \text{ or GND}; I_O = 0 \text{ A}$	-	0.2	10	μΑ		
ΔI_{CC}	additional supply current	per input pin; $V_{CC} = 3.0 \text{ V}$ to 3.6 V; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$	-	5	750	μΑ		
Cı	input capacitance		-	3.5	-	pF		

^[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see <u>Figure 7</u>.

Symbol	Parameter	Conditions	T _{amb} =	Unit			
				Min	Typ[1]	Max	
t_{pd}	propagation delay	CP to Qn; see Figure 6	[2]				ns ns ns
		V _{CC} = 1.65 V to 1.95 V		1.0	2.8	4.7	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.0	2.0	3.1	ns
		V _{CC} = 2.7 V		1.0	2.2	2.9	ns
		V _{CC} = 3.0 V to 3.6 V		1.0	2.0	2.8	ns
C _{PD}	power dissipation capacitance	per gate; $V_I = GND$ to V_{CC} ; $V_{CC} = 3.3 \text{ V}$	[3]	-	25	-	pF

^[1] Typical values are measured at $T_{amb} = 25 \, ^{\circ}\text{C}$

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

f_i = input frequency in MHz; f_o = output frequency in MHz

C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs

^[2] t_{pd} is the same as t_{PHL} and t_{PLH} .

^[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

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11. Waveforms

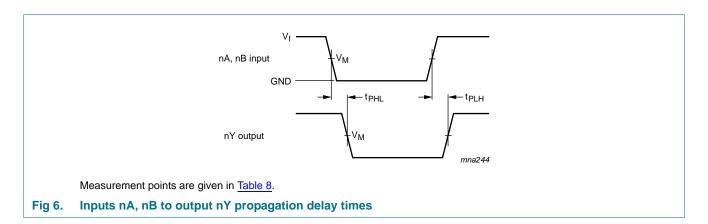
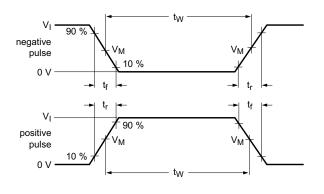
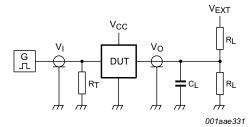


Table 8. Measurement points

Supply voltage V _{CC}	Input V _I	V _M
1.65 V to 1.95 V	V_{CC}	0.5V _{CC}
2.3 V to 2.7 V	V _{CC}	0.5V _{CC}
2.7 V	2.7 V	1.5 V
3.0 V to 3.6 V	2.7 V	1.5 V

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Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 7. Test circuitry for measuring switching times

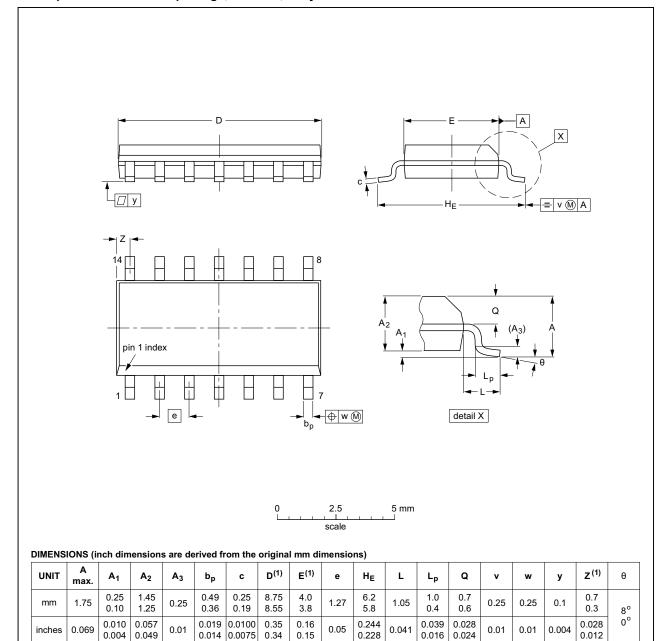
Table 9. Test data

Supply voltage V _{CC}	Input		Load		V _{EXT}	V _{EXT}			
	VI	V_{l} t_{r} , t_{f} C_{L}		R _L	t_{PLH} , t_{PHL}	t_{PLZ}, t_{PZL}	t_{PHZ} , t_{PZH}		
1.65 V to 1.95 V	V_{CC}	\leq 2.0 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND		
2.3 V to 2.7 V	V_{CC}	≤ 2.0 ns	30 pF	500Ω	open	$2\times V_{CC}$	GND		
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500Ω	open	6 V	GND		
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500Ω	open	6 V	GND		

12. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

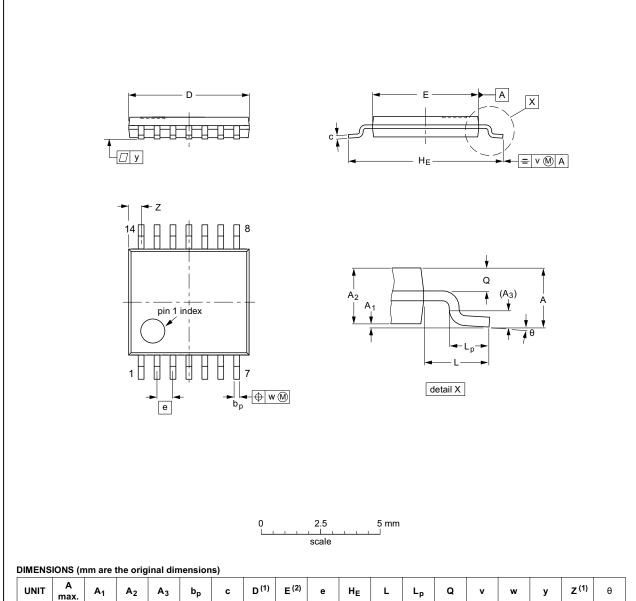
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012				99-12-27 03-02-19	

Fig 8. Package outline SOT108-1 (SO14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT402-1		MO-153				99-12-27 03-02-18

Fig 9. Package outline SOT402-1 (TSSOP14)

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

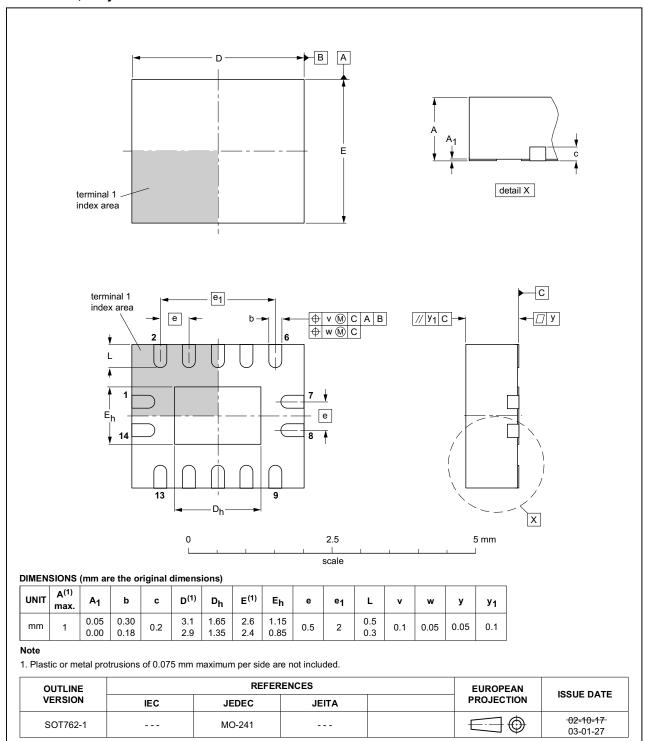


Fig 10. Package outline SOT762-1 (DHVQFN14)

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74ALVC32 v.3	20140120	Product data sheet	-	74ALVC32 v.2		
	 The format of to of NXP Semice 	this data sheet has been red onductors.	esigned to comply with	the new identity guidelines		
	 Legal texts have been adapted to the new company name where appropriate. 					
74ALVC32 v.2	20071210	Product data sheet	-	74ALVC32 v.1		
74ALVC32 v.1	20021115	Product specification	-	-		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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